PATENT COOPERATION TREATY

Translation **PCT**

INTERNATIONAL PRELIMINARY REPORT ON PATENTABILITY (Chapter II of the Patent Cooperation Treaty)

(PCT Article 36 and Rule 70)

Applicant's or agent's file reference 543-60.762PCT/AP/zi			FOR FURTHER ACT	ΓΙΟΝ	See Form PCT/IPEA/416					
International application No.			International filing date	(day/month/year)	Priority date (day/month/year)					
PCT/EP2004/004841			06.05.2004		07.05.2003					
	International Patent Classification (IPC) or national classification and IPC									
michanonal Fatem Classification (IPC) of national classification and IPC										
Applicant										
PERKINELMER OPTOELECTRONICS GMBH & CO. KG										
1.										
	under Article 35 and transmitted to the applicant according to Article 36.									
2.	This REPORT cons	sists of a total of	/	sheets, including	g this cover sheet.					
3.	This report is also a	accompanied by A	NNEXES, comprising:							
	a. (sent to	the applicant and	to the International Bure	au) a total of 4	sheets, as follows:					
	101			•	amended and are the basis for this report and/or					
	sheets containing rectifications authorized by this Authority (see Rule 70.16 and Section 607 of the Administrative Instructions).									
	sheets which supersede earlier sheets, but which this Authority considers contain an amendment that goes beyond the disclosure in the international application as filed, as indicated in item 4 of Box No. I and the Supplemental									
	Box.									
	b. (sent to the International Bureau only) a total of (indicate type and number of electronic carrier(s))									
					, containing a sequence listing and/or tables					
	related the	ereto, in compute	r readable form only, as i	indicated in the Supple	emental Box Relating to Sequence Listing (see					
	Section 8	02 of the Adminis	trative Instructions).							
4.	This report contain	s indications relat	ing to the following items	:						
	Box No. I	Basis of th	e report							
1	Box No. II	Priority								
	Box No. II	I Non-establ	ishment of opinion with re	egard to novelty, invent	tive step and industrial applicability					
	Box No. IV	/ Lack of un	ity of invention							
	$\overline{\square}$		•	(2) with regard to pove	elty, inventive step or industrial applicability;					
	Box No. V		nd explanations supporting		on, memore step of modstrial approaching,					
	Box No. V	I Certain do	cuments cited							
	Box No. V	II Certain de	fects in the international a	pplication						
	Box No. VIII Certain observations on the international application									
Date of	sub mission of the de	mand	Tr	Date of completion of the	nis report					
2 and an analysis of the committee				and or completion of the						
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Facsim	ile No.			Telephone No.						

INTERNATIONAL PRELIMINARY REPORT ON PATENTABILITY

International application No.

PCT/EP2004/004841 Box No. I Basis of the report With regard to the language, this report is based on the international application in the language in which it was filed, unless otherwise indicated under this item. This report is based on translations from the original language into the following language which is the language of a translation furnished for the purposes of: international search (Rule 12.3 and 23.1(b)) publication of the international application (Rule 12.4) international preliminary examination (Rule 55.2 and/or 55.3) With regard to the elements of the international application, this report is based on (replacement sheets which have been furnished to the receiving Office in response to an invitation under Article 14 are referred to in this report as "originally filed" and are not annexed to this report): the international application as originally filed/furnished the description: as originally filed/furnished pages received by this Authority on pages* received by this Authority on pages* the claims: as originally filed/furnished as amended (together with any statement) under Article 19 received by this Authority on nos.* received by this Authority on nos.* the drawings: as originally filed/furnished _____ received by this Authority on received by this Authority on a sequence listing and/or any related table(s) - see Supplemental Box Relating to Sequence Listing. The amendments have resulted in the cancellation of: the description, pages the claims, nos. the drawings, sheets/figs the sequence listing (specify): any table(s) related to sequence listing (specify): This report has been established as if (some of) the amendments annexed to this report and listed below had not been made, since they have been considered to go beyond the disclosure as filed, as indicated in the Supplemental Box (Rule 70.2(c)). the description, pages __ the claims, nos.

the drawings, sheets/figs

the sequence listing (specify): any table(s) related to sequence listing (specify): If item 4 applies, some or all of those sheets may be marked "superseded."

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	ште			REI ORI ONTATENTABELITI	PCT/EP2004/0048	41
Box	No. V			ticle 35(2) with regard to novelty, inventive s	tep or industrial applicability;	
1.	Statement		waviis su	Shorang and statement	<u>'.</u>	
	Novelt	y (N)	Claime	1-15		YES
	()		Claims			NO
Inventive des (IS)					1 /20	
Inventive step (IS)		Claims			YES NO	
					_	
	Industrial applicability (IA)			1-15		
			Claims			_ NO
2.	Citations	and explanations (Rule 7	0.7)			
	Refe	rence is mad	de to	the following docume	nts:	
	D1:	EP-A-0 599	364	(MATSUSHITA ELECTRIC	WORKS LTD),	
		1 June 199	4 (19	94-06-01)		
	D2:	DE 101 44	343 A	. (PERKINELMER OPTOELE	CTRONICS GM),	
				2003-03-27)		
		 -	- \	•		
	1.	The applic	ation	fails to meet the re	quirements of	
	-•			(1) because the subjec		
				-		
_		t claim 1 does not involve an inventive Article 33(3)).				
		scep (FCI	ALUIC	,10 33(3//•		
		Dogument D	1 4:5	scloses the following	(see figures 57 +	0
				_		<u> </u>
				15, lines 45 to 47 in		
		the refere	nces	in parentheses are to	, דע (דע (
				,		
			iatio	on sensor ("infrared d	etector 14")	
		with				
		– a s	subst	rate ("substrate 12")	,	
		- a (cavit	y ("cavity") formed i	n one surface of	
		the	e sub	strate, which may be	a depression or a	
		th	rough	-hole,		
		– a	senso	r element ("infrared	detector 14")	

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Box No. V Reasoned statement under Article 35(2) with regard to novelty, inventive step or industrial applicability; citations and explanations supporting such statement

- over the cavity, preferably on a membrane spanning the cavity ("thermally infrared absorbing film 13"), and
- electrical contacts for the sensor element (see elements 16Qa and 16Qb in figure 59),

characterised in that

- the cavity in the surface of the substrate has a fully or partially rounded contour (see figure 59).

The subject matter of claim 1 differs from the known radiation sensor in that at least a portion of the lateral wall of the cavity is perpendicular to the surface of the substrate, and in that the cavity is created by dry etching.

The problem addressed by the present invention can thus be seen as that of designing a radiation sensor that makes better use of the space (see the discussion about wasted space on page 4 of the description).

The solution proposed in claim 1 of the application cannot be considered inventive (PCT Article 33(3)) for the following reasons:

Document D2 states (see paragraph 5) that particularly small radiation sensors can be produced by ion etching. This is because of the vertical lateral walls that can by obtained using such a process (see column 2, lines 1

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Box No. V Reasoned statement under Article 35(2) with regard to novelty, inventive step or industrial applicability; citations and explanations supporting such statement

and 2). Hence the solution to the technical problem of interest is known in its entirety from D2.

2. The application fails to meet the requirements of PCT Article 33(1) because the subject matter of independent claim 15 does not involve an inventive step (PCT Article 33(3)).

Document D1, which is considered to be the prior art closest to the subject matter of claim 15, discloses the following (see the description, column 10, line 1 to column 11, line 37; the references in parentheses are to D1):

Process for producing a radiation sensor, comprising the following steps:

- producing a flat wafer ("silicon substrate"),
- applying an etching stop layer ("silicon oxide film") to a first surface of the wafer, followed by a mechanically stable membrane ("nitride film"),
- applying an etching mask to a second surface of the wafer (there is no mention of an etching mask in the description, but those skilled in the art know that such masks are used in the process in question (KOH etching)), the etching mask having one or more openings with an at least partially rounded contour (this variant is shown in figure 59 and described at column 15, lines 45 to 47), and
- etching cavities in the wafer, starting from the

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Box No. V Reasoned statement under Article 35(2) with regard to novelty, inventive step or industrial applicability; citations and explanations supporting such statement

second surface and proceeding towards the etching stop layer ("the cavity 11G is formed in the substrate 12G on the side opposite to that having the infrared detector 14G, by means of the anisotropic etching carried out with potassium hydroxide").

The subject matter of claim 15 differs from the known, process for producing a radiation sensor in that a dry etching process is used.

The problem addressed by the present invention can thus be seen as that of designing a radiation sensor that makes better use of the space (see the discussion about wasted space on page 4 of the description).

The solution proposed in claim 15 of the application cannot be considered inventive (PCT Article 33(3)) for the following reasons:

Document D2 states (see paragraph 5) that particularly small radiation sensors can be produced by ion etching. This is because of the vertical lateral walls that can by obtained using such a process (see column 2, lines 1 and 2). Hence the solution to the technical problem of interest is known in its entirety from D2.

3. Dependent claims 2 to 14 do not contain any features that meet the PCT requirements in respect of novelty or inventive step when combined with the features of any of the back-referenced claims. The reasons for this are as follows:

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Box No. V Reasoned statement under Article 35(2) with regard to novelty, inventive step or industrial applicability; citations and explanations supporting such statement							
	citations and capitaliauous supporting such statement						
	Claims 2-4, 6-	-8, 10-13:	Additional features disclosed				
			in D1 (see figures 52 to 54,				
			59, 61 and 63; column 10,				
			line 1 to column 11, line 37,				
			and column 15, lines 45 to 47)				
			(PCT Article 33(2)).				
	Claim 5:		Additional features known				
	orarm o.		from a comparable radiation				
			sensor (see D2, paragraph				
			42) (PCT Article 33(3)).				
			, , , = = = = = = = = = = = = = = = = =				
	Claim 9:		The figures seem to be within				
			the normal range for				
			micromechanical radiation				
			detectors. The proportions				
			specified for the cavity				
			diameter follow directly from				
			the round shape of the cavity				
			and the square contour, both				
			of which are known from D1				
			(PCT Article 33(3)).				
	Claim 14:		The effect of imaging elements				
			such as mirrors and lenses are				
			generally known in the art in				
			the context of optical				
			radiation detectors (PCT				
			Article 33(3)).				
•			1				